

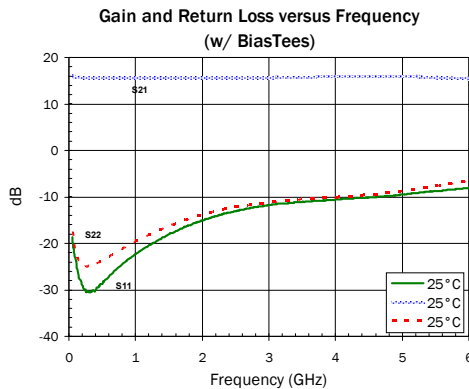


### Product Description

RFMD's SBB4089Z is a high performance InGaP HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SBB4089Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SBB4089Z product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to 50Ωs.

#### Optimum Technology Matching® Applied

- GaAs HBT
- GaAs MESFET
- InGaP HBT
- SiGe BiCMOS
- Si BiCMOS
- SiGe HBT
- GaAs pHEMT
- Si CMOS
- Si BJT
- GaN HEMT
- RF MEMS



### Features

- OIP<sub>3</sub> = 35.2dBm at 1950MHz
- P<sub>1dB</sub> = 19.3dBm at 1950MHz
- Single Fixed 5V Supply
- Robust 1000V ESD, Class 1C
- Patented Thermal Design & Bias Circuit
- Low Thermal Resistance

### Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- Wideband Instrumentation
- Wireless Data, Satellite Terminals

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Small Signal Gain	14.0	15.5	17.0	dB	850MHz
	13.8	15.0	17.0	dB	1950MHz
	13.5	15.5	17.5	dB	2000MHz
Output Power at 1dB Compression		19.0		dBm	850MHz
		18.0	19.2	dBm	1950MHz
Output Third Order Intercept Point		39.0		dBm	850MHz
		33.0	35.3	dBm	1950MHz
Return Loss		4500		MHz	Minimum 10dB
Input Return Loss	10.0	16.3		dB	1950MHz
Output Return Loss	10.0	18.0		dB	1950MHz
Reverse Isolation		18.5		dB	1950MHz
Noise Figure		4.3	5.5	dB	1950MHz
Operating Temp Range (T <sub>L</sub> )	-40		+105	°C	
Device Operating Voltage		5.0	5.25	V	
Device Operating Current	70.0	80.0	92.0	mA	
Thermal Resistance		69.9		°C/W	junction - lead

Test Conditions: V<sub>D</sub> = 5V I<sub>D</sub> = 80mA Typ. OIP<sub>3</sub> Tone Spacing = 1MHz, P<sub>OUT</sub> per tone = 0dBm T<sub>L</sub> = 25°C, Z<sub>S</sub> = Z<sub>L</sub> = 50Ω, Tested with Bias Tees

## Absolute Maximum Ratings

Parameter	Rating	Unit
Device Current ( $I_D$ )	100	mA
Max Device Voltage (VD)	5.5	V
Max RF Input Power	24	dBm
Max Operating Dissipated Power	0.55	W
Junction Temp ( $T_J$ )	+150	°C
Storage Temp	+150	°C
ESD Rating - Human Body Model (HBM)	Class 1C	
Moisture Sensitivity Level	MSL2	



**Caution!** ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

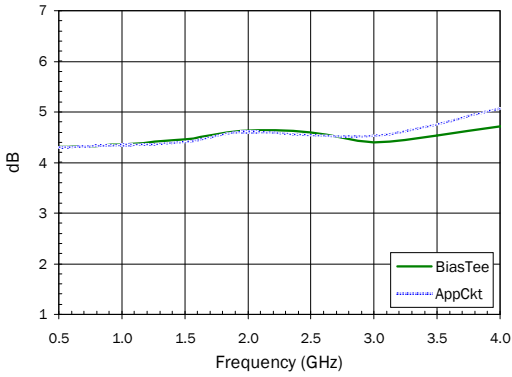
$$I_D V_D < (T_J - T_L) / R_{TH}, J-I \text{ and } T_L = T_{LEAD}$$

## Typical Performance at Key Operating Frequencies (With 0.5GHz to 3.5GHz Application Circuit)

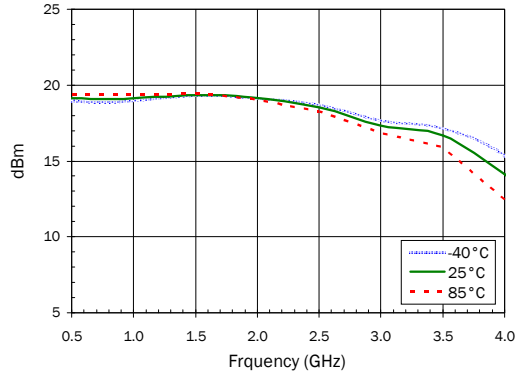
Parameter	Unit	50 MHz	100 MHz	200 MHz	500 MHz	850 MHz	1950 MHz	2500 MHz	3500 MHz	4000 MHz
Small Signal Gain	dB	16.3	15.7	15.7	15.6	15.6	15.5	15.5	15.5	15.0
Output Third Order Intercept Point	dBm	38.7	40.6	39.7	38.8	39.3	35.2	32.8	29.1	26.1
Output Power at 1dB Compression	dBm	18.5	18.7	19	19.2	19.1	19.2	18.6	16.7	14.1
Input Return Loss	dB	11.2	16.3	22.4	25.1	29.9	19.4	17.6	14.9	21.3
Output Return Loss	dB	19.4	25.4	29.8	32.1	26.4	17.2	14.7	13.2	17.4
Reverse Isolation	dB	17.7	17.8	17.8	18.4	18.4	18.9	19.1	19.8	20.8
Noise Figure	dB	4.3	4.3	4.3	4.3	4.3	4.6	4.5	4.8	5.1

Test Conditions: VCC=5V,  $I_D$ =80mA Typ., OIP<sub>3</sub> Tone Spacing=1MHz, P<sub>OUT</sub> per tone=0dBm, T<sub>L</sub>=25°C, Z<sub>S</sub>=Z<sub>L</sub>=50Ω

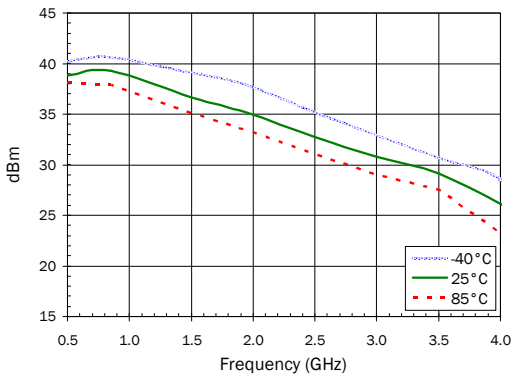
Noise Figure @ 25 °C



P1dB versus Frequency with App. Ckt.

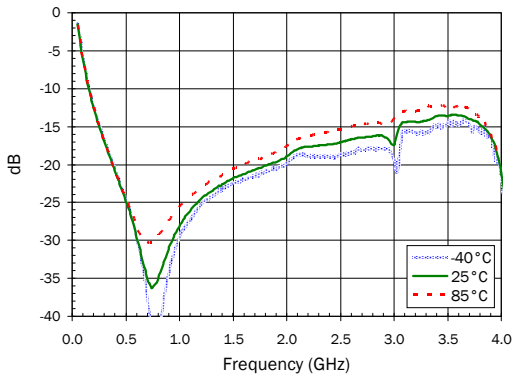


OIP3 versus Frequency with App. Ckt.

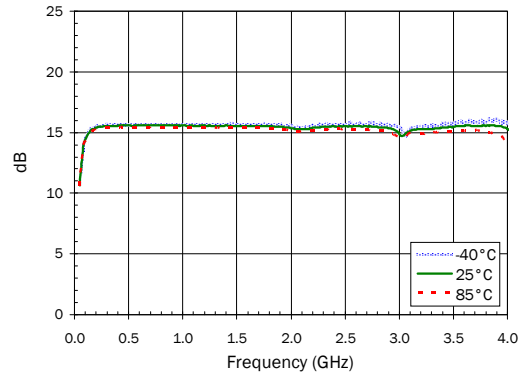


## 0.5GHz to 3.5GHz Application Circuit S-Parameters over Temperature

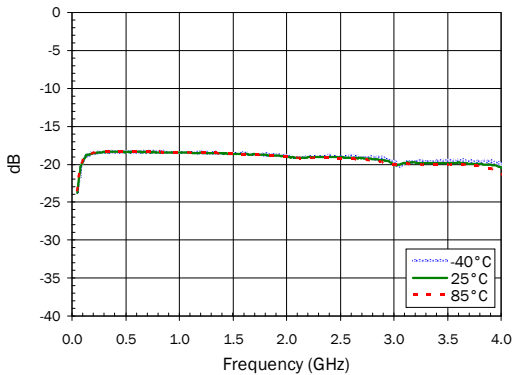
### S11 versus Frequency



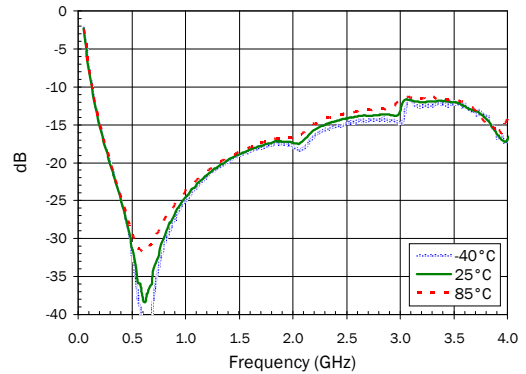
### S21 versus Frequency



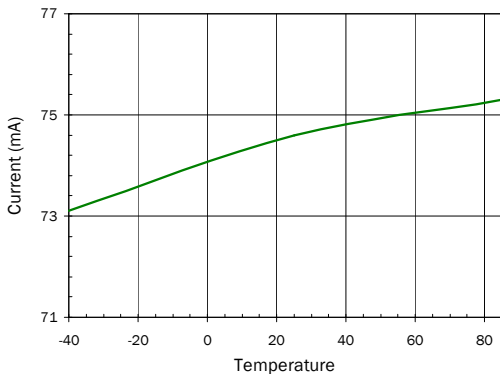
### S12 versus Frequency



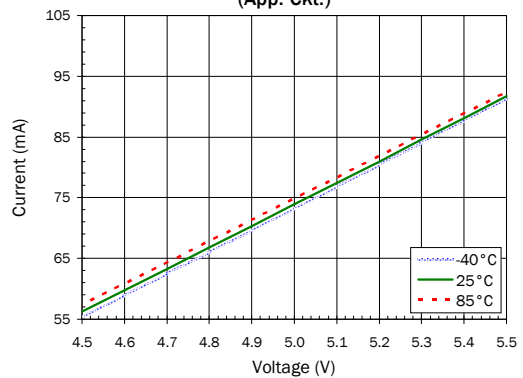
### S22 versus Frequency



### I<sub>D</sub> versus Temperature

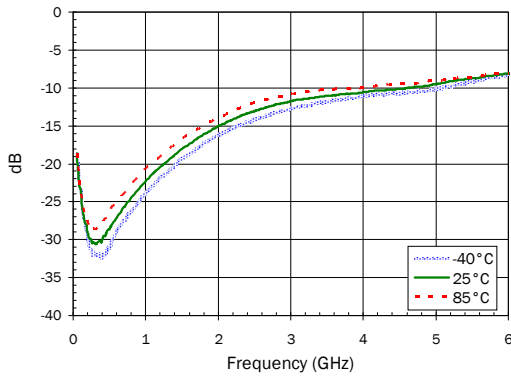


### Current versus Voltage Over Temp. (App. Ckt.)

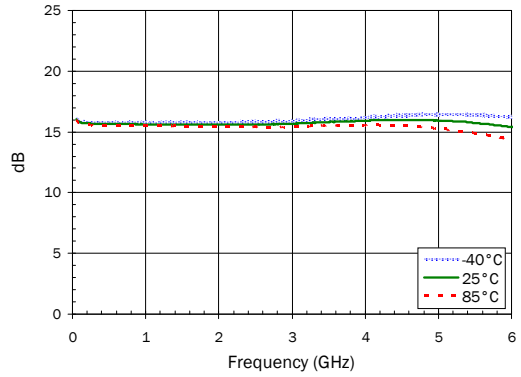


S-Parameters over Temperature (Bias Tee)

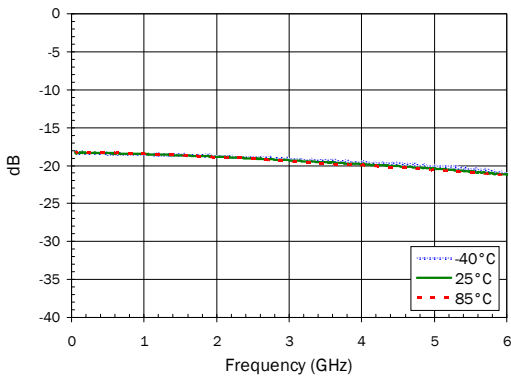
S11 versus Frequency



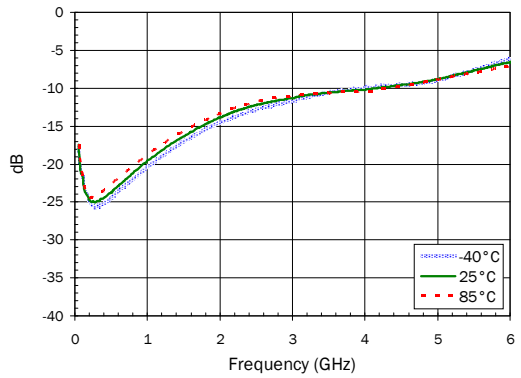
S21 versus Frequency



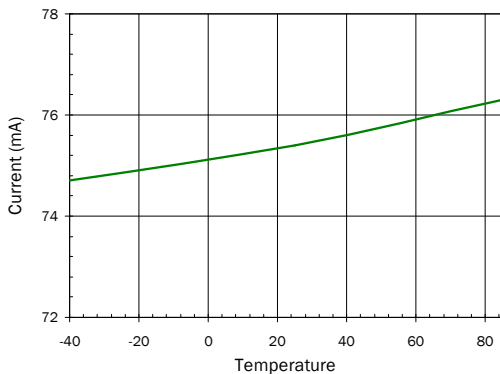
S12 versus Frequency



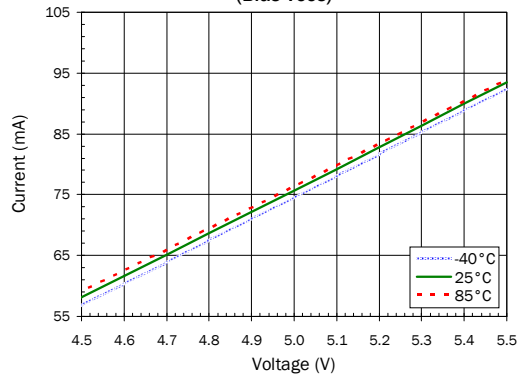
S22 versus Frequency



I<sub>D</sub> versus Temperature

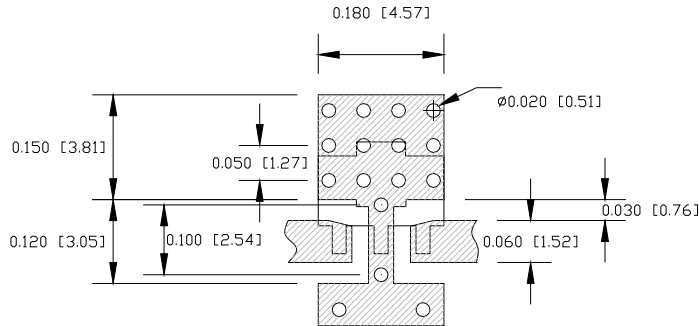


Current versus Voltage Over Temp. (Bias Tees)



Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation

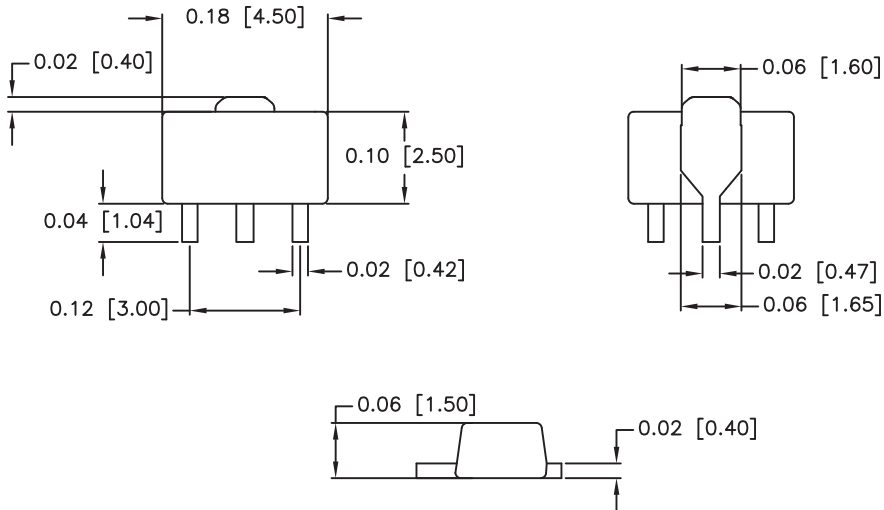
## Suggested PCB Pad Layout



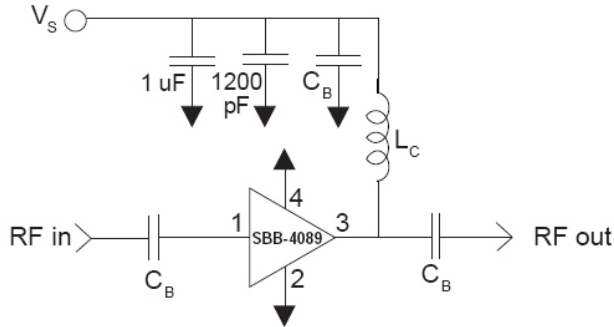
## Package Drawing

Dimensions in inches (millimeters)

Refer to drawing posted at [www.rfmd.com](http://www.rfmd.com) for tolerances.



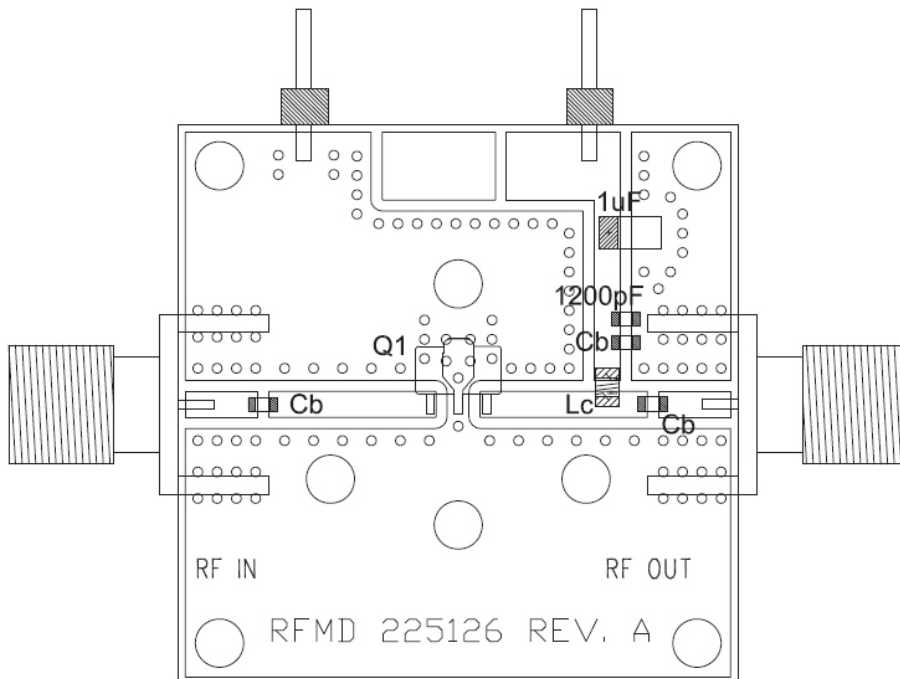
## Application Schematic



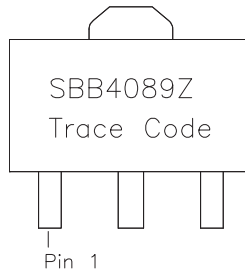
Reference Designator	Frequency (MHz) 500 to 3500
$C_B$	68 pF
$L_C$	82 nH 0805CS

**Note:** For frequencies under 500MHz make the following changes:  
 $C_B = .1\mu F$   
 $L_C = 330\text{ nH}$

## Evaluation Board Layout and Bill of Materials



## Package Marking



## Ordering Information

Ordering Code	Description
SBB4089Z	7" Reel with 1000 pieces
SBB4089ZSQ	Sample Bag with 25 pieces
SBB4089ZSR	7" Reel with 100 pieces
SBB4089ZPCK1	1 Evaluation Board (500MHz to 3500MHz) with 5-piece Sample Bag